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Class	ISSUE C
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U.S. UTILITY Patent Application

O.I.P.E. TM TDY TM

PATENT DATE

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/682151		257	7.58	8.15	<i>[Signature]</i>

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APPLICANTS
Martin Kordesch
Howard Bartlow
Richard Woodin

TITLE
Contact method for thin silicon carbide epitaxial layer and semiconductor devices formed by those methods

PTO-2040
(12/89)

CLASSIFICATION